New Jersey Semi-Conductor Products, Inc.

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## **GOLD BONDED GERMANIUM DIODE**

### **FEATURES**

Low forward voltage drop—low power consumption Thirty years of proven reliability—one million hours mean time between failures (MTBF) Very low noise level Metallurgically bonded

# ABSOLUTE MAXIMUM RATINGS (at 25 °C, unless otherwise specified)

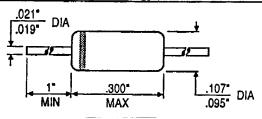
Peak Inverse Voltage Peak Forward Current Operating Temperature Range Average Power Dissipation

100 Volts 500 mA - 65 °C to 85 °C 80 mW

# **ELECTRICAL CHARACTERISTICS**

· · · · ·	Symbol	Conditions	Min	Max	Unit	T ℃	Ī
Peak Inverse Voltage Reverse Current	PIV Ir	1 mA 100 V	100	600	V μA	25 °C 25 °C	
Forward Voltage	Vf	4 mA		1	v	25 °C	

### MECHANICAL





NJ Semi-Conductors reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by NJ Semi-Conductors is believed to be both accurate and reliable at the time of going to press. However, NJ Semi-Conductors assumes no responsibility for any errors or omissions discovered in its use. NJ Semi-Conductors encourages customers to verify that datasheets are current before placing orders.

### **Quality Semi-Conductors**